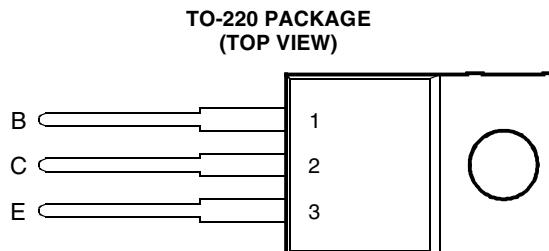


- Designed for Complementary Use with TIP115, TIP116 and TIP117
- 50 W at 25°C Case Temperature
- 4 A Continuous Collector Current
- Minimum  $h_{FE}$  of 500 at 4V, 2 A

**!** This series is obsolete and not recommended for new designs.



Pin 2 is in electrical contact with the mounting base.

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### absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	TIP110	$V_{CBO}$	60	V
	TIP111	$V_{CBO}$	80	
	TIP112	$V_{CBO}$	100	
Collector-emitter voltage ( $I_B = 0$ )	TIP110	$V_{CEO}$	60	V
	TIP111	$V_{CEO}$	80	
	TIP112	$V_{CEO}$	100	
Emitter-base voltage		$V_{EBO}$	5	V
Continuous collector current		$I_C$	4	A
Peak collector current (see Note 1)		$I_{CM}$	6	A
Continuous base current		$I_B$	50	mA
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		$P_{tot}$	50	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		$P_{tot}$	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}LI_C^2$	25	mJ
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		$T_L$	260	°C

NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%$ .

2. Derate linearly to 150°C case temperature at the rate of 0.4 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20$  mH,  $I_{B(on)} = 5$  mA,  $R_{BE} = 100 \Omega$ ,  $V_{BE(off)} = 0$ ,  $R_S = 0.1 \Omega$ ,  $V_{CC} = 20$  V.

### PRODUCT INFORMATION

**electrical characteristics at 25°C case temperature**

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage (see Note 5)	$I_C = 30 \text{ mA}$	$I_B = 0$	TIP110 TIP111 TIP112	60 80 100			V
$I_{CEO}$ Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$	$I_B = 0$	TIP110 TIP111 TIP112			2 2 2	mA
$I_{CBO}$ Collector cut-off current	$V_{CB} = 60 \text{ V}$ $V_{CB} = 80 \text{ V}$ $V_{CB} = 100 \text{ V}$	$I_E = 0$	TIP110 TIP111 TIP112			1 1 1	mA
$I_{EBO}$ Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				2	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$	$I_C = 1 \text{ A}$ $I_C = 2 \text{ A}$	(see Notes 5 and 6)	1000 500			
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 8 \text{ mA}$	$I_C = 2 \text{ A}$	(see Notes 5 and 6)			2.5	V
$V_{BE}$ Base-emitter voltage	$V_{CE} = 4 \text{ V}$	$I_C = 2 \text{ A}$	(see Notes 5 and 6)			2.8	V
$V_{EC}$ Parallel diode forward voltage	$I_E = 4 \text{ A}$	$I_B = 0$	(see Notes 5 and 6)			3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

**resistive-load-switching characteristics at 25°C case temperature**

PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
$t_{on}$ Turn-on time	$I_C = 2 \text{ A}$	$I_{B(on)} = 8 \text{ mA}$	$I_{B(off)} = -8 \text{ mA}$		2.6		$\mu\text{s}$
$t_{off}$ Turn-off time	$V_{BE(off)} = -5 \text{ V}$	$R_L = 15 \Omega$	$t_p = 20 \mu\text{s}$ , dc $\leq 2\%$		4.5		$\mu\text{s}$

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

**PRODUCT INFORMATION**

## TYPICAL CHARACTERISTICS

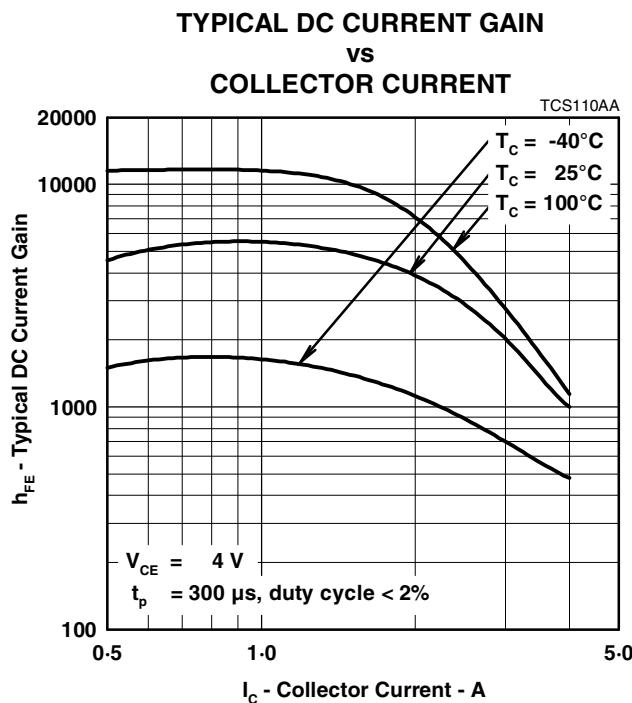


Figure 1.

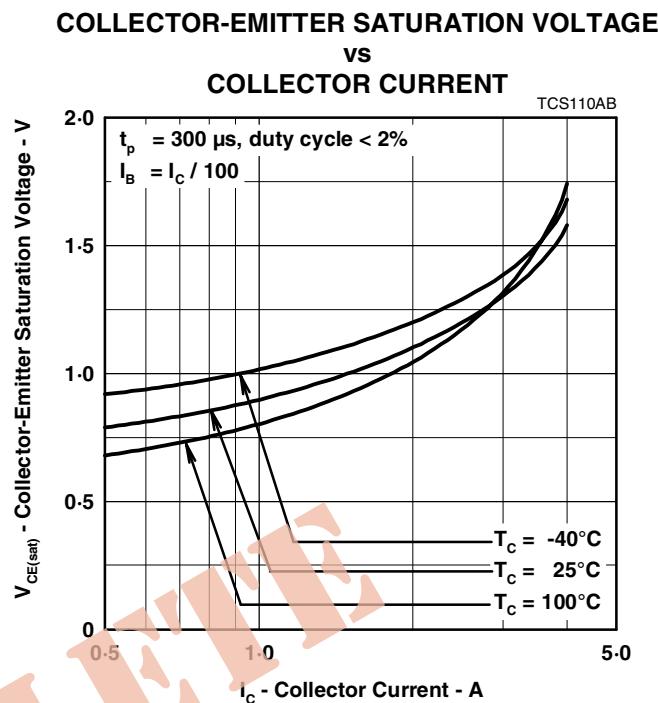


Figure 2.

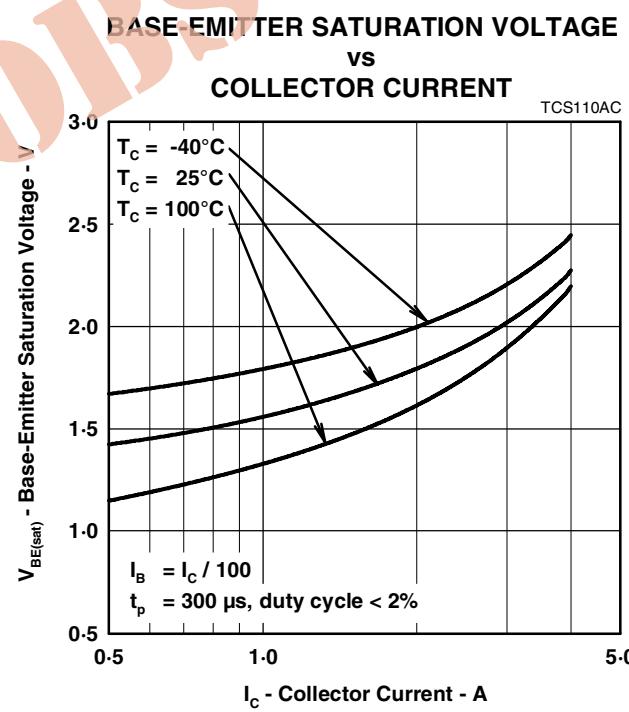


Figure 3.

**PRODUCT INFORMATION**

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Specifications are subject to change without notice.

### MAXIMUM SAFE OPERATING REGIONS

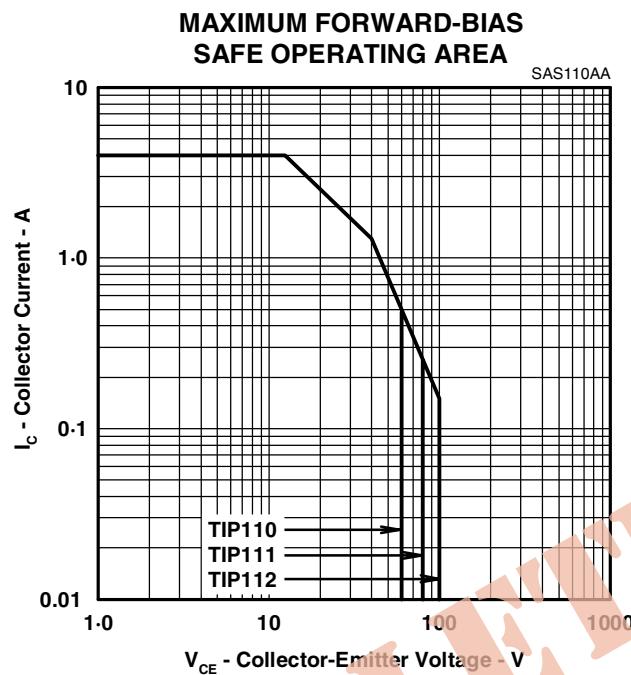


Figure 4.

### THERMAL INFORMATION

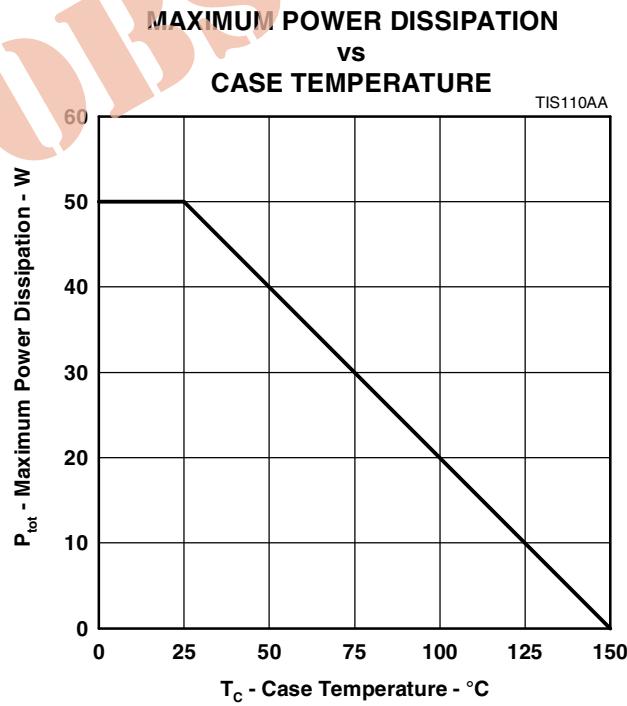


Figure 5.

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